

# RJK03M5DPA

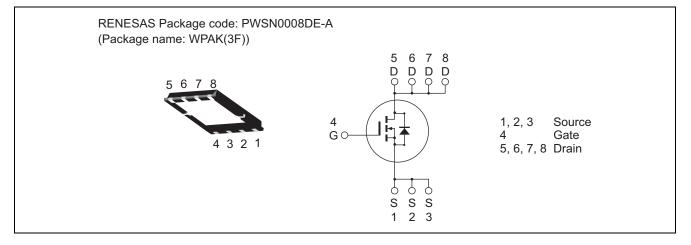
30V, 30A, 6.5mΩmax. N Channel Power MOS FET High Speed Power Switching

R07DS0770EJ0200 Rev.2.00 Feb 12 2013

#### Features

- High speed switching
- Capable of 4.5 V gate drive
- Low drive current
- High density mounting
- Low on-resistance
- Pb-free
- Halogen-free

## Outline



## **Absolute Maximum Ratings**

			$(Ta = 25^{\circ}C)$	
Item	Symbol	Ratings	Unit	
Drain to source voltage	V <sub>DSS</sub>	30	V	
Gate to source voltage	V <sub>GSS</sub>	±20	V	
Drain current	Ι <sub>D</sub>	30	А	
Drain peak current	Note1 I <sub>D(pulse)</sub>	120	А	
Body-drain diode reverse drain current	I <sub>DR</sub>	30	А	
Avalanche current	I <sub>AP</sub> Note 2	10.5	А	
Avalanche energy	E <sub>AS</sub> Note 2	11	mJ	
Channel dissipation	Pch Note3	30	W	
Channel to case thermal impedance	θch-c <sup>Note3</sup>	4.2	°C/W	
Channel temperature	Tch	150	°C	
Storage temperature	Tstg	-55 to +150	°C	
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Notes: 1.  $PW \le 10 \ \mu s$ , duty cycle  $\le 1\%$ 

2. Value at Tch = 25°C, Rg  $\ge$  50  $\Omega$ 

3. Tc = 25°C



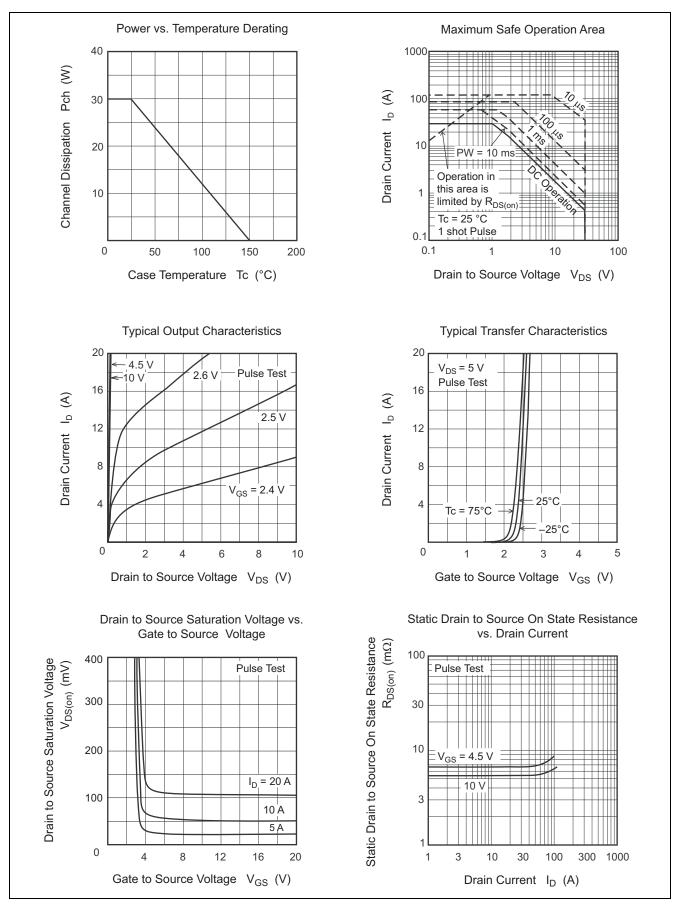
# **Electrical Characteristics**

			r _			$(Ta = 25^{\circ}C)$
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain to source breakdown voltage	V <sub>(BR)DSS</sub>	30	_	—	V	$I_{D}$ = 10 mA, $V_{GS}$ = 0
Gate to source leak current	I <sub>GSS</sub>	—	—	± 0.5	μA	$V_{GS}$ = ±20 V, $V_{DS}$ = 0
Zero gate voltage drain current	I <sub>DSS</sub>	—	—	1	μA	$V_{DS}$ = 24 V, $V_{GS}$ = 0
Gate to source cutoff voltage	V <sub>GS(off)</sub>	1.2	—	2.5	V	$V_{DS}$ = 10 V, I <sub>D</sub> = 1 mA
Static drain to source on state	R <sub>DS(on)</sub>	—	5.4	6.5	mΩ	$I_D$ = 15 A, $V_{GS}$ = 10 V <sup>Note4</sup>
resistance	R <sub>DS(on)</sub>	—	6.6	8.6	mΩ	$I_D$ = 15 A, $V_{GS}$ = 4.5 V <sup>Note4</sup>
Forward transfer admittance	y <sub>fs</sub>	_	70	_	S	$I_D$ = 15 A, $V_{DS}$ = 5 V <sup>Note4</sup>
Input capacitance	Ciss	_	1350	1890	pF	V <sub>DS</sub> = 10 V
Output capacitance	Coss	_	220	_	pF	V <sub>GS</sub> = 0 f = 1 MHz
Reverse transfer capacitance	Crss	_	120	_	pF	
Gate Resistance	Rg	_	1.4	2.8	Ω	
Total gate charge	Qg	_	10.4	_	nC	V <sub>DD</sub> = 10 V
Gate to source charge	Qgs	_	4.0		nC	V <sub>GS</sub> = 4.5 V I <sub>D</sub> = 30 A
Gate to drain charge	Qgd	_	3.1	_	nC	
Turn-on delay time	t <sub>d(on)</sub>	_	3.7	_	ns	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 15 A
Rise time	tr	_	3.0	_	ns	V <sub>DD</sub> ≅ 10 V R <sub>L</sub> = 0.67 Ω Rg = 4.7 Ω
Turn-off delay time	t <sub>d(off)</sub>	_	21.7	_	ns	
Fall time	t <sub>f</sub>	_	7.0	_	ns	
Body–drain diode forward voltage	V <sub>DF</sub>		0.87	1.13	V	$I_F = 30 \text{ A}, V_{GS} = 0^{\text{Note4}}$
Body–drain diode reverse recovery	t <sub>rr</sub>		8.8		ns	I <sub>F</sub> =30 A, V <sub>GS</sub> = 0
time						di <sub>F</sub> / dt = 500 A/ μs

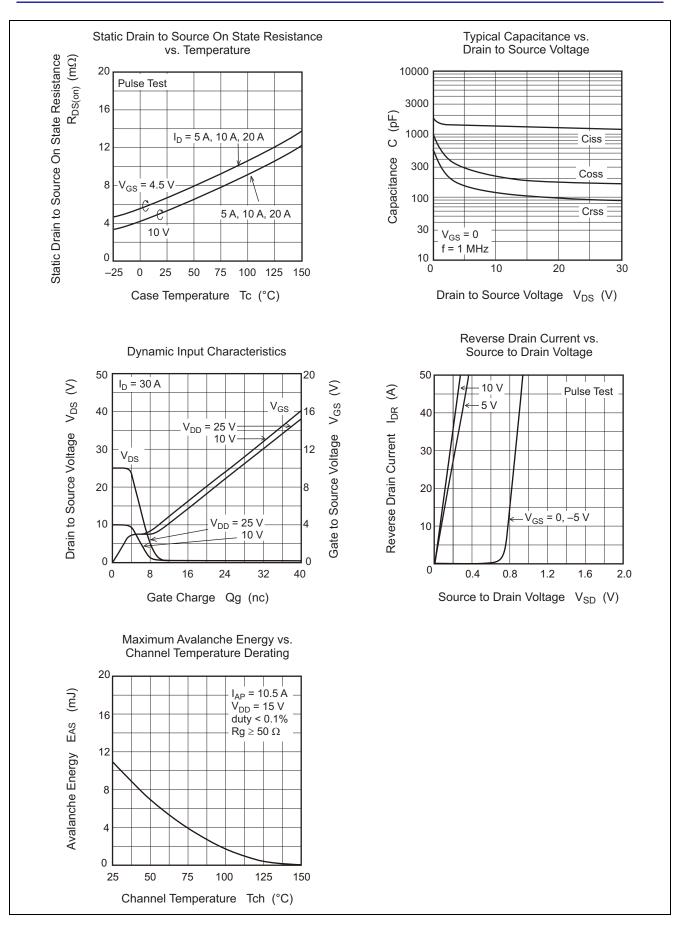
Notes: 4. Pulse test

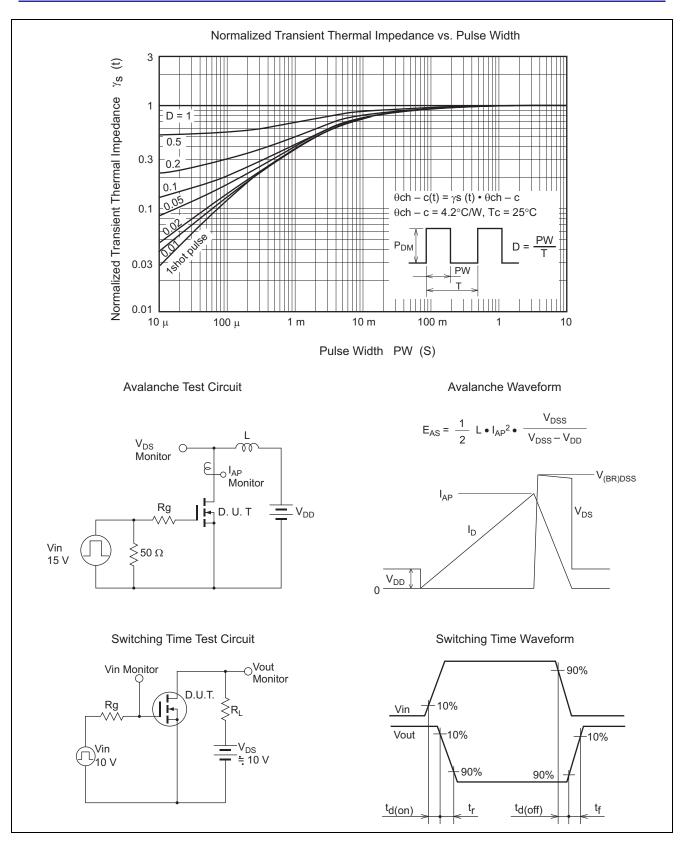


#### **Main Characteristics**

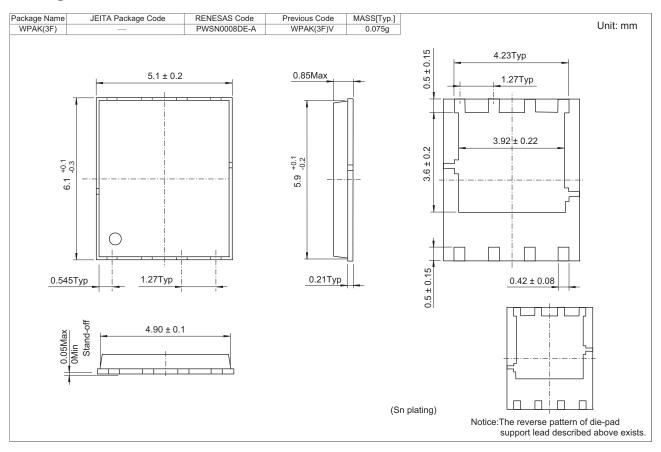








## **Package Dimensions**



## **Ordering Information**

Orderable Part Number	Quantity	Shipping Container
RJK03M5DPA-00-J5A	3000 pcs	Taping

Note: The symbol of 2nd "-" is occasionally presented as "#".



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